



EV318285893

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. .... 10/087,416  
Filing Date ..... February 27, 2002  
Inventor ..... Jigish D. Trivedi et al.  
Assignee ..... Micron Technology, Inc.  
Group Art Unit ..... 2811  
Examiner ..... Douglas W. Owens  
Attorney's Docket No. .... MI22-1965  
Title: MOS Transistors With Nitrogen in the Gate Oxide of the P-Channel Transistor

**RESPONSE TO JULY 31, 2003 OFFICE ACTION**

To: Mail Stop Non-Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

From: D. Brent Kenady  
Tel. 509-624-4276; Fax 509-838-3424  
Wells St. John P.S.  
601 West First Avenue, Suite 1300  
Spokane, WA 99201-3828

Responsive to the Office Action dated July 31, 2003, Applicant amends  
and remarks as follows:

**AMENDMENTS**

Underlines indicate insertions and ~~strikeouts~~ indicate deletions.

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